

## CD4093BM/CD4093BC Quad 2-Input NAND Schmitt Trigger

### General Description

The CD4093B consists of four Schmitt-trigger circuits. Each circuit functions as a 2-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive and negative-going signals. The difference between the positive ( $V_T^+$ ) and the negative voltage ( $V_T^-$ ) is defined as hysteresis voltage ( $V_H$ ).

All outputs have equal source and sink currents and conform to standard B-series output drive (see Static Electrical Characteristics).

### Features

- Wide supply voltage range 3.0V to 15V
- Schmitt-trigger on each input with no external components
- Noise immunity greater than 50%

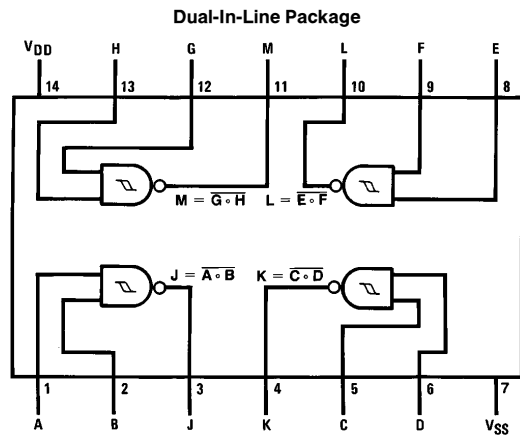
- Equal source and sink currents
- No limit on input rise and fall time
- Standard B-series output drive
- Hysteresis voltage (any input)  $T_A = 25^\circ\text{C}$

Typical	$V_{DD} = 5.0\text{V}$	$V_H = 1.5\text{V}$
	$V_{DD} = 10\text{V}$	$V_H = 2.2\text{V}$
	$V_{DD} = 15\text{V}$	$V_H = 2.7\text{V}$
Guaranteed		$V_H = 0.1 V_{DD}$

### Applications

- Wave and pulse shapers
- High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND logic

### Connection Diagram



TL/F/5982-1

Top View

Order Number CD4093B

**Absolute Maximum Ratings** (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage ( $V_{DD}$ )	–0.5 to +18 $V_{DC}$
Input Voltage ( $V_{IN}$ )	–0.5 to $V_{DD}$ + 0.5 $V_{DC}$
Storage Temperature Range ( $T_S$ )	–65°C to +150°C
Power Dissipation ( $P_D$ )	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature ( $T_L$ )	
(Soldering, 10 seconds)	260°C

**Recommended Operating Conditions** (Note 2)

DC Supply Voltage ( $V_{DD}$ )	3 to 15 $V_{DC}$
Input Voltage ( $V_{IN}$ )	0 to $V_{DD}$ $V_{DC}$
Operating Temperature Range ( $T_A$ )	
CD4093BM	–55°C to +125°C
CD4093BC	–40°C to +85°C

**DC Electrical Characteristics** CD4093BM (Note 2)

Symbol	Parameter	Conditions	–55°C		+25°C			+125°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
$I_{DD}$	Quiescent Device Current	$V_{DD} = 5V$		0.25			0.25		7.5	$\mu A$
		$V_{DD} = 10V$		0.5			0.5		15.0	$\mu A$
		$V_{DD} = 15V$		1.0			1.0		30.0	$\mu A$
$V_{OL}$	Low Level Output Voltage	$V_{IN} = V_{DD},  I_O  < 1 \mu A$								
		$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
$V_{OH}$	High Level Output Voltage	$V_{IN} = V_{SS},  I_O  < 1 \mu A$								
		$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		V
$V_{T^-}$	Negative-Going Threshold Voltage (Any Input)	$ I_O  < 1 \mu A$								
		$V_{DD} = 5V, V_O = 4.5V$	1.3	2.25	1.5	1.8	2.25	1.5	2.3	V
		$V_{DD} = 10V, V_O = 9V$	2.85	4.5	3.0	4.1	4.5	3.0	4.65	V
		$V_{DD} = 15V, V_O = 13.5V$	4.35	6.75	4.5	6.3	6.75	4.5	6.9	V
$V_{T^+}$	Positive-Going Threshold Voltage (Any Input)	$ I_O  < 1 \mu A$								
		$V_{DD} = 5V, V_O = 0.5V$	2.75	3.65	2.75	3.3	3.5	2.65	3.5	V
		$V_{DD} = 10V, V_O = 1V$	5.5	7.15	5.5	6.2	7.0	5.35	7.0	V
		$V_{DD} = 15V, V_O = 1.5V$	8.25	10.65	8.25	9.0	10.5	8.1	10.5	V
$V_H$	Hysteresis ( $V_{T^+} - V_{T^-}$ ) (Any Input)	$V_{DD} = 5V$	0.5	2.35	0.5	1.5	2.0	0.35	2.0	V
		$V_{DD} = 10V$	1.0	4.30	1.0	2.2	4.0	0.70	4.0	V
		$V_{DD} = 15V$	1.5	6.30	1.5	2.7	6.0	1.20	6.0	V
$I_{OL}$	Low Level Output Current (Note 3)	$V_{IN} = V_{DD}$								
		$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
$I_{OH}$	High Level Output Current (Note 3)	$V_{IN} = V_{SS}$								
		$V_{DD} = 5V, V_O = 4.6V$	–0.64		0.51	–0.88		–0.36		mA
		$V_{DD} = 10V, V_O = 9.5V$	–1.6		–1.3	–2.25		–0.9		mA
		$V_{DD} = 15V, V_O = 13.5V$	–4.2		–3.4	–8.8		–2.4		mA
$I_{IN}$	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		–0.1		–10 <sup>–5</sup>	–0.1		–1.0	$\mu A$
		$V_{DD} = 15V, V_{IN} = 15V$		0.1		10 <sup>–5</sup>	0.1		1.0	$\mu A$

**Note 1:** “Absolute Maximum Ratings” are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of “Recommended Operating Conditions” and “Electrical Characteristics” provides conditions for actual device operation.

**Note 2:**  $V_{SS} = 0V$  unless otherwise specified.

**Note 3:**  $I_{OH}$  and  $I_{OL}$  are tested one output at a time.

## DC Electrical Characteristics CD4093BC (Note 2)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
$I_{DD}$	Quiescent Device Current	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		1.0 2.0 4.0			1.0 2.0 4.0		7.5 15.0 30.0	$\mu A$ $\mu A$ $\mu A$
$V_{OL}$	Low Level Output Voltage	$V_{IN} = V_{DD},  I_O  < 1 \mu A$ $V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		0.05 0.05 0.05		0 0 0	0.05 0.05 0.05		0.05 0.05 0.05	V V V
$V_{OH}$	High Level Output Voltage	$V_{IN} = V_{SS},  I_O  < 1 \mu A$ $V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$	4.95 9.95 14.95		4.95 9.95 14.95	5 10 15		4.95 9.95 14.95		V V V
$V_{T^-}$	Negative-Going Threshold Voltage (Any Input)	$ I_O  < 1 \mu A$ $V_{DD} = 5V, V_O = 4.5V$ $V_{DD} = 10V, V_O = 9V$ $V_{DD} = 15V, V_O = 13.5V$	1.3 2.85 4.35	2.25 4.5 6.75	1.5 3.0 4.5	1.8 4.1 6.3	2.25 4.5 6.75	1.5 3.0 4.5	2.3 4.65 6.9	V V V
$V_{T^+}$	Positive-Going Threshold Voltage (Any Input)	$ I_O  < 1 \mu A$ $V_{DD} = 5V, V_O = 0.5V$ $V_{DD} = 10V, V_O = 1V$ $V_{DD} = 15V, V_O = 1.5V$	2.75 5.5 8.25	3.6 7.15 10.65	2.75 5.5 8.25	3.3 6.2 9.0	3.5 7.0 10.5	2.65 5.35 8.1	3.5 7.0 10.5	V V V
$V_H$	Hysteresis ( $V_{T^+} - V_{T^-}$ ) (Any Input)	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$	0.5 1.0 1.5	2.35 4.3 6.3	0.5 1.0 1.5	1.5 2.2 2.7	2.0 4.0 6.0	0.35 0.70 1.20	2.0 4.0 6.0	V V V
$I_{OL}$	Low Level Output Current (Note 3)	$V_{IN} = V_{DD}$ $V_{DD} = 5V, V_O = 0.4V$ $V_{DD} = 10V, V_O = 0.5V$ $V_{DD} = 15V, V_O = 1.5V$	0.52 1.3 3.6		0.44 1.1 3.0	0.88 2.25 8.8		0.36 0.9 2.4		mA mA mA
$I_{OH}$	High Level Output Current (Note 3)	$V_{IN} = V_{SS}$ $V_{DD} = 5V, V_O = 4.6V$ $V_{DD} = 10V, V_O = 9.5V$ $V_{DD} = 15V, V_O = 13.5V$	−0.52 −1.3 −3.6		0.44 −1.1 −3.0	−0.88 −2.25 −8.8		−0.36 −0.9 −2.4		mA mA mA
$I_{IN}$	Input Current	$V_{DD} = 15V, V_{IN} = 0V$ $V_{DD} = 15V, V_{IN} = 15V$		−0.3 0.3		$-10^{-5}$ $10^{-5}$	−0.3 0.3		−1.0 1.0	$\mu A$ $\mu A$

## AC Electrical Characteristics\*

$T_A = 25^\circ C$ ,  $C_L = 50$  pF,  $R_L = 200k$ , Input  $t_r$ ,  $t_f = 20$  ns, unless otherwise specified

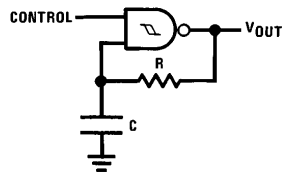
Symbol	Parameter	Conditions	Min	Typ	Max	Units
$t_{PHL}, t_{PLH}$	Propagation Delay Time	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		300 120 80	450 210 160	ns ns ns
$t_{THL}, t_{TLH}$	Transition Time	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		90 50 40	145 75 60	ns ns ns
$C_{IN}$	Input Capacitance	(Any Input)		5.0	7.5	pF
$C_{PD}$	Power Dissipation Capacitance	(Per Gate)		24		pF

\*AC Parameters are guaranteed by DC correlated testing.

**Note 2:**  $V_{SS} = 0V$  unless otherwise specified.

**Note 3:**  $I_{OH}$  and  $I_{OL}$  are tested one output at a time.

## Typical Applications



Assume  $t_1 + t_2 \gg t_{pHL} + t_{pLH}$  then:

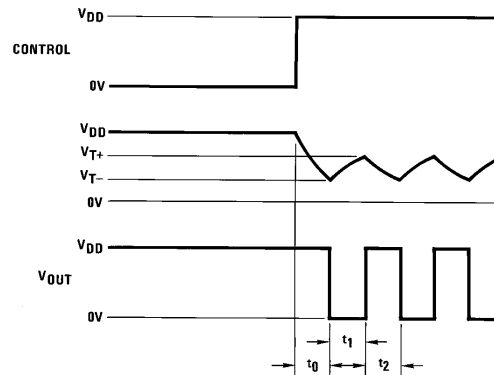
$$t_0 = RC \ln [V_{DD}/V_{T-}]$$

$$t_1 = RC \ln [(V_{DD} - V_{T-})/(V_{DD} - V_{T+})]$$

$$t_2 = RC \ln [V_{T+}/V_{T-}]$$

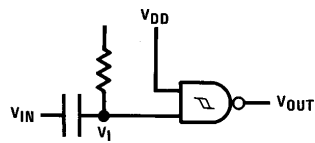
$$f = \frac{1}{t_1 + t_2} = \frac{1}{RC \ln \frac{(V_{T+})(V_{DD} - V_{T-})}{(V_{T-})(V_{DD} - V_{T+})}}$$

### Gated Oscillator

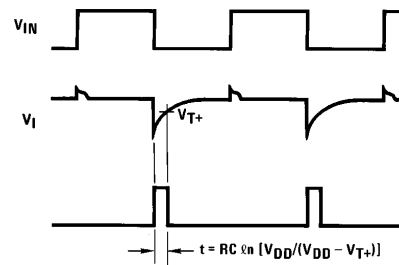


TL/F/5982-3

### Gated One-Shot

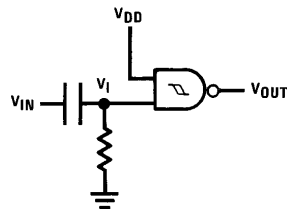


TL/F/5982-4

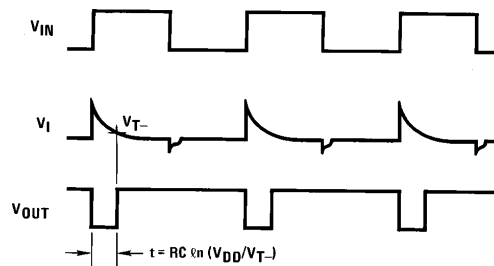


TL/F/5982-5

#### (a) Negative-Edge Triggered



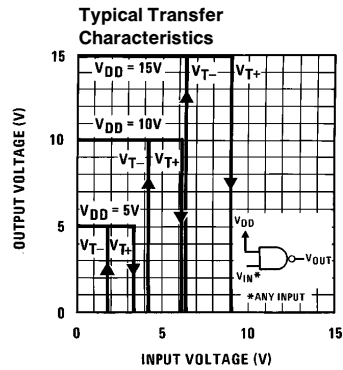
TL/F/5982-6



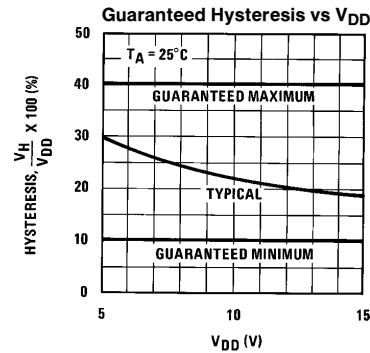
TL/F/5982-7

#### (b) Positive-Edge Triggered

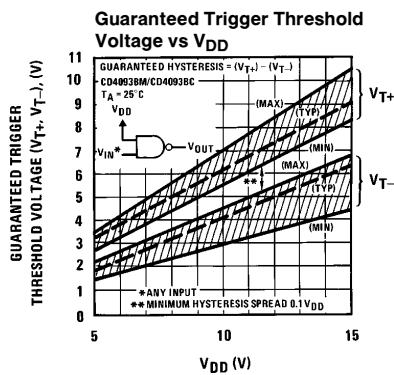
## Typical Performance Characteristics



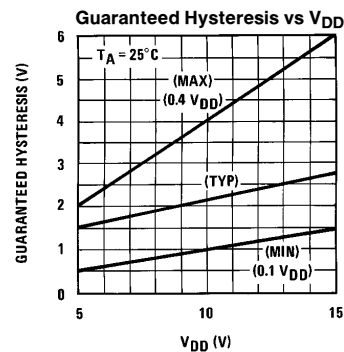
TL/F/5982-8



TL/F/5982-9

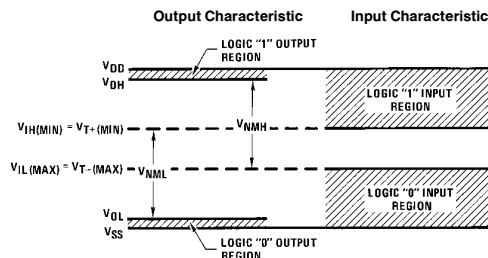
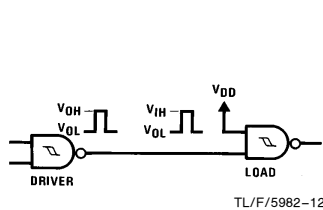


TL/F/5982-10



TL/F/5982-11

## Input and Output Characteristics

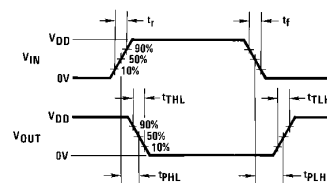
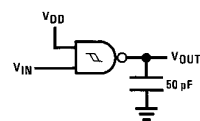


TL/F/5982-13

$$V_{NML} = V_{IH(MIN)} - V_{OL} \approx V_{IH(MIN)} = V_{T+ (MIN)}$$

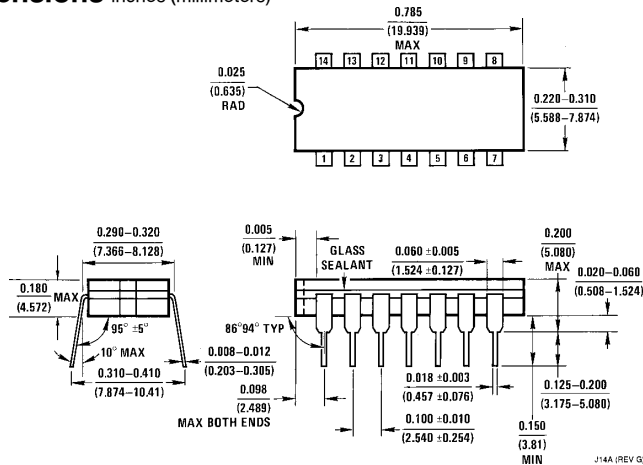
$$V_{NMH} = V_{OH} - V_{IL(MAX)} \approx V_{DD} - V_{IL(MAX)} = V_{DD} - V_{T- (MAX)}$$

## AC Test Circuits and Switching Time Waveforms

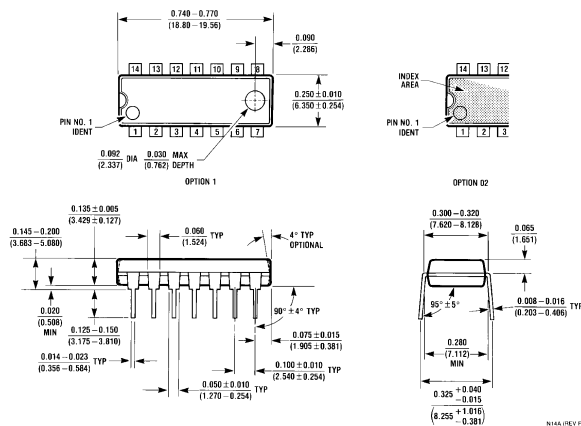


TL/F/5982-15

## Physical Dimensions inches (millimeters)



**Ceramic Dual-In-Line Package (J)**  
**Order Number CD4093BMJ or CD4093BCJ**  
**NS Package Number J14A**



**Molded Dual-In-Line Package (N)**  
**Order Number CD4093BM or CD4093BCN**  
**NS Package Number N14A**

### LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



**National Semiconductor Corporation**  
 1111 West Bardin Road  
 Arlington, TX 76017  
 Tel: 1(800) 272-9959  
 Fax: 1(800) 737-7018

**National Semiconductor Europe**  
 Fax: (+49) 0-180-530 85 86  
 Email: cnjwge@tevm2.nsc.com  
 Deutsch Tel: (+49) 0-180-530 85 85  
 English Tel: (+49) 0-180-532 78 32  
 Français Tel: (+49) 0-180-532 93 58  
 Italiano Tel: (+49) 0-180-534 16 80

**National Semiconductor Hong Kong Ltd.**  
 19th Floor, Straight Block,  
 Ocean Centre, 5 Canton Rd.  
 Tsimshatsui, Kowloon  
 Hong Kong  
 Tel: (852) 2737-1600  
 Fax: (852) 2736-9960

**National Semiconductor Japan Ltd.**  
 Tel: 81-043-299-2309  
 Fax: 81-043-299-2408